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Cite this: *J. Mater. Chem. C*, 2023, **11**, 3889

DOI: 10.1039/d3tc90046k

rsc.li/materials-c

Correction: Recent advances in single crystal narrow band-gap semiconductor nanomembranes and their flexible optoelectronic device applications: Ge, GeSn, InGaAs, and 2D materials

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Correction for 'Recent advances in single crystal narrow band-gap semiconductor nanomembranes and their flexible optoelectronic device applications: Ge, GeSn, InGaAs, and 2D materials' by Shu An *et al.*, *J. Mater. Chem. C*, 2023, **11**, 2430–2448, <https://doi.org/10.1039/d2tc05041b>.

The authors wish to note that in the published article, both the first and second authors should be marked with the † footnote symbol to indicate that they contributed equally.

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The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

